



# NCE N-Channel Enhancement Mode Power MOSFET

## Description

The NCE6050 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

### **General Features**

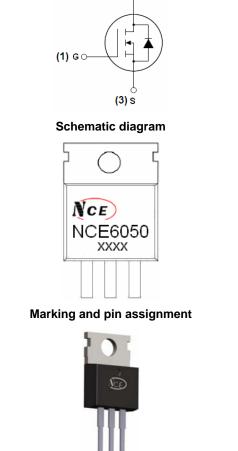
- V<sub>DS</sub> =60V,I<sub>D</sub> =50A
  R<sub>DS(ON)</sub> <20mΩ @ V<sub>GS</sub>=10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

# Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

**100% ΔVds TESTED!** 



(2) D

TO-220-3L top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6050	NCE6050	TO-220-3L	-	-	-

#### Absolute Maximum Ratings (T<sub>A</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	60	V	
Gate-Source Voltage	VGS	±20	V	
Drain Current-Continuous	Ι <sub>D</sub>	50	А	
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	35	А	
Pulsed Drain Current	I <sub>DM</sub>	220	A	
Maximum Power Dissipation	PD	80	W	
Derating factor		0.53	W/°C	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	115	mJ	



**Pb Free Product** 

NCE6050

Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 175	°C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	1.88	°C <b>/W</b>
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#### Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	60	71	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	1.2	2.0	2.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	17	20	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =25V,I <sub>D</sub> =20A	24	-	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C <sub>lss</sub>		-	900	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}=25V, V_{GS}=0V,$	-	104	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	33	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	25	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =30V,I <sub>D</sub> =2A,R <sub>L</sub> =15Ω	-	5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V,R <sub>G</sub> =2.5Ω	-	50	-	nS
Turn-Off Fall Time	t <sub>f</sub>			6	-	nS
Total Gate Charge	Qg	)/ _20)// _504	-	30		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =30V,I <sub>D</sub> =50A, V <sub>GS</sub> =10V	-	10		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	5		nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	50	A
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 40A	-	50	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	100	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is neglig	gible (turi	n-on is do	ominated b	y LS+LD)

## Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board, t  $\leq$  10 sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

5. EAS condition: Tj=25 $^\circ\!\mathrm{C}$ ,V\_{DD}=30V,V\_G=10V,L=0.5mH,Rg=25\Omega

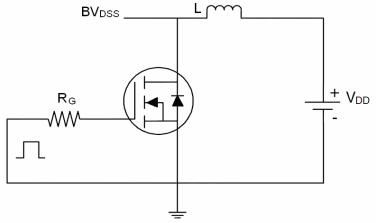


Pb Free Product

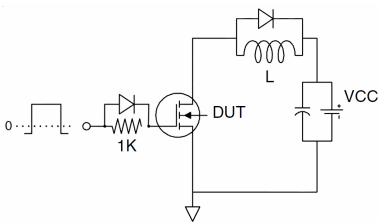


# **Test circuit**

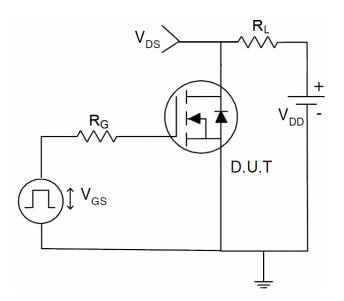
1)  $E_{AS}$  test Circuits



2) Gate charge test Circuit:



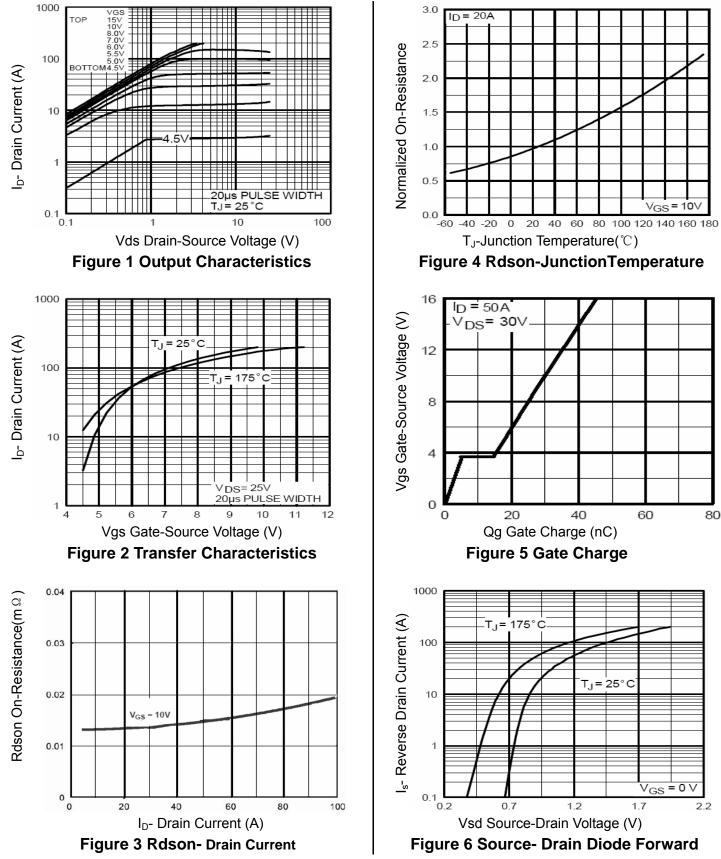
3) Switch Time Test Circuit:







# **Typical Electrical and Thermal Characteristics (Curves)**









100

V<sub>DS</sub>=V<sub>GS</sub>

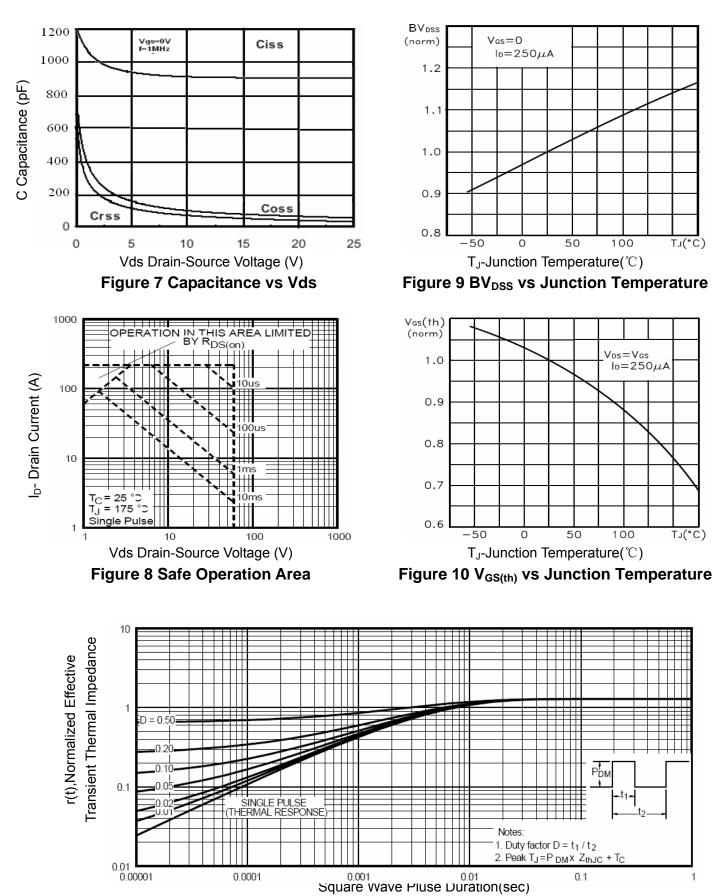
100

PDN

I₀=250µA

TJ(°C)

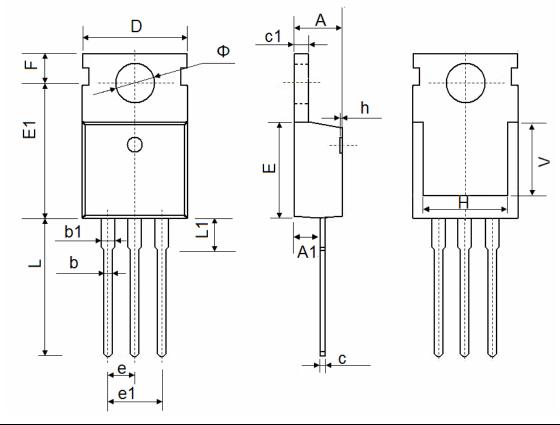
TJ(°C)







# **TO-220-3L Package Information**



Symbol	Dimensions	In Millimeters	Dimension	s In Inches		
	Min.	Max.	Min.	Max.		
А	4.400	4.600	0.173	0.181		
A1	2.250	2.550	0.089	0.100		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
С	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
D	9.910	10.250	0.390	0.404		
E	8.9500	9.750	0.352	0.384		
E1	12.650	12.950	0.498	0.510		
е	2.540	) TYP.	0.100	0.100 TYP.		
e1	4.980	5.180	0.196	0.204		
F	2.650	2.950	0.104	0.116		
Н	7.900	8.100	0.311	0.319		
h	0.000	0.300	0.000	0.012		
L	12.900	13.400	0.508	0.528		
L1	2.850	3.250	0.112	0.128		
V	7.500	) REF.	0.295	REF.		
Φ	3.400	3.800	0.134	0.150		







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